SY75602A/02B/603A/03B/604A/04B

2/4 Outputs Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 Clock Buffer

Features

- Two (SY75602A/02B/603A/03B) and Four (SY75604A/04B) PCIe 1.0, 2.0, 3.0, 4.0, 5.0, and 6.0 Compliant Outputs.
- Ultra-Low Additive Jitter 10 fs (PCIe Gen5) and 6 fs (PCIe Gen6)
- Supports Frequencies of up to 250 MHz
- Transparent for Spread Spectrum
- Supports 1.8V ±10%, 2.5V ±10%, and 3.3V ±10% Power Supplies
- Outputs Low Power HCSL with Embedded 85Ω (SY75602A/03A/04A) and 100Ω (SY75602B/03B/04B) Termination Resistors
- Individual Glitch Free Output Enable (OExb) Control Pins on SY75603/604
- Accepts DC-Coupled HCSL Input Signal and AC-Coupled PECL, LVDS, and CML
- Extended Temperature Range: –40°C to +105°C
- 1.4 mm x 1.6 mm VDFN (SY75602A/02B) and 3 mm x 3 mm VQFN (SY75603A/03B/604A/04B) Package

Applications

- PCIe Graphics Cards
- PCIe Based SSD drives
- Laptops and Desktop Computers
- Servers

General Description

The SY75602A/02B/03A/03B/04A/04B are industry leading PCIe clock buffers with ultra-low additive jitter:

- 6 fs (PCIe 6.0)
- 10 fs (PCIe 5.0)
- 20 fs (PCIe 3.0/4.0)
- 52 fs in 12 kHz to 20 MHz band

They can be used in all PCIe 1/2/3/4/5/6 common clock and SRIS applications.

SY75602A/02B are the industry's smallest (1.4 mm x 1.6 mm VDFN) two output PCIe clock buffers.

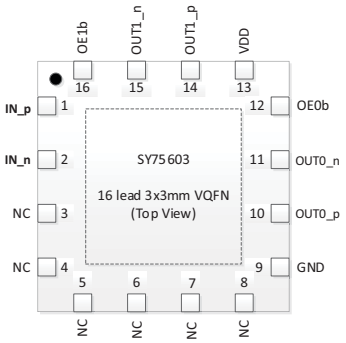
SY75603A/03B and SY75604A/04B are two and four output PCIe clock buffers with glitch free per-output enable/disable control hardware pins. Both devices are packaged in 3 mm x 3 mm VQFN.

The devices have embedded low-dropout regulators (LDO) for superior power noise supply rejection. They support 1.8V, 2.5V, and 3.3V supplies with tolerance of ±10% which exceeds ±9% required by PCIe Card Electro Mechanical Specification.

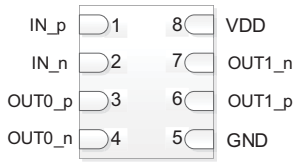
All six parts have extended temperature range: –40°C to +105°C.

Package Types

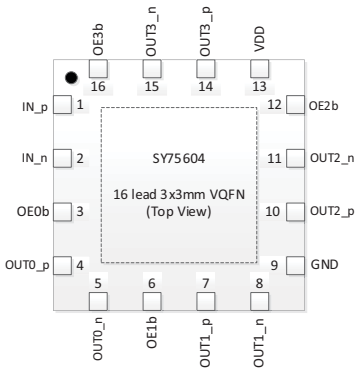
SY75603
16-Lead 3 mm x 3 mm VQFN
Top View



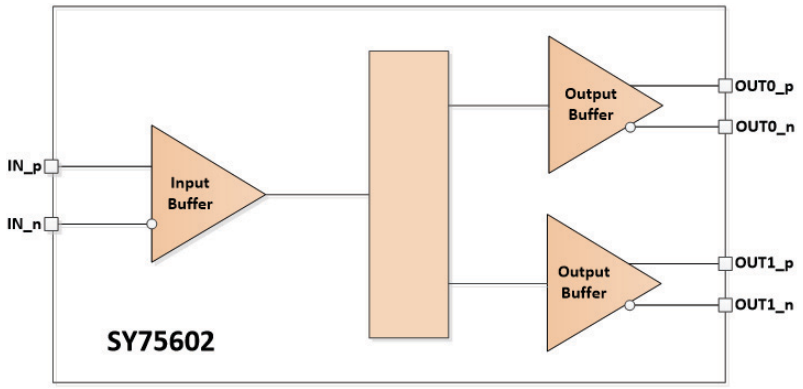
SY75602
8-Lead 1.4 mm x 1.6 mm VDFN
Top View

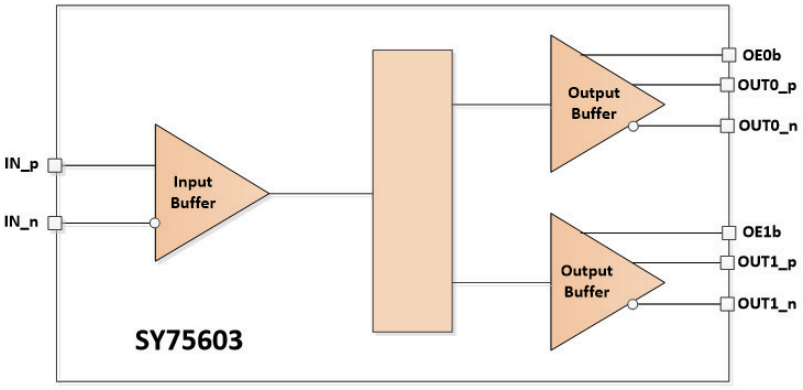


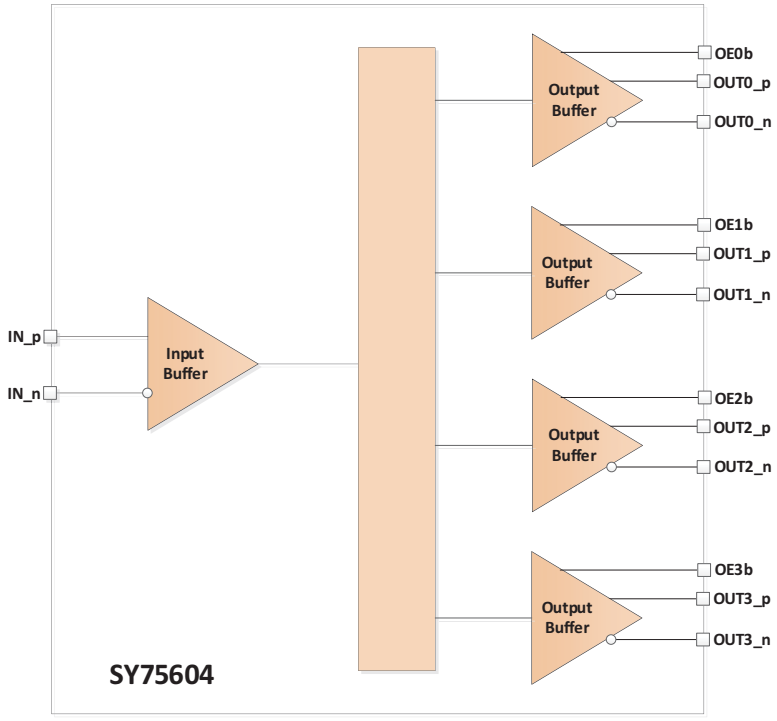
SY75604
16-Lead 3 mm x 3 mm VQFN
Top View



Functional Block Diagrams







1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V_{DD}).....–0.5V to +4.6V
Input Voltage (V_{IN}) ..... –0.5V to V_{DD} +0.5V
Input ESD Protection (HBM)..... 2 kV

Operating Ratings ‡

1.8V Operating Voltage (V_{DD}).....+1.62V to +1.98V
2.5V Operating Voltage (V_{DD}).....+2.25V to +2.75V
3.3V Operating Voltage (V_{DD}).....+2.97V to +3.63V

† Notice: Permanent device damage may occur if absolute maximum ratings are exceeded. This is a stress rating only and functional operation is not implied at conditions other than those detailed in the operational sections of this data sheet. Exposure to absolute maximum ratings conditions may affect device reliability.

‡ Notice: The data sheet limits are not ensured if the device is operated beyond the recommended operating conditions.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10%; T_A = –40°C to +105°C, unless noted.

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Current Consumption						
Core Device Current	I_{DD}	—	9	13	mA	SY75602, Output current excluded (no load)
		—	9	13		SY75603/04, all outputs disabled
Current dissipation per each LP-HCSL output (100Ω)	$I_{OUT\_HCSL\_100\Omega}$	—	3.5	3.9	mA	Note 1
Current dissipation per each LP-HCSL output (85Ω)	$I_{OUT\_HCSL\_85\Omega}$	—	4.0	4.4	mA	Note 1
Power Supply Noise Rejection Ratio Characteristics						
Power Supply Noise Rejection Ratio	$PSNRR_{HSCL}$	—	70	—	dB	100 mV_{PP}, 100 kHz noise injected to V_{DD}. Clock Frequency 100 MHz, V_{DD} = 3.3V
Input Characteristics						
Input Slew Rate	SR_{IN}	0.6	—	—	V/ns	—
Differential Input High Voltage	V_{IH}	0.15	—	—	V	—
Differential Input Low Voltage	V_{IL}	—	—	–0.15	V	—
Input Voltage Swing	V_{SWING}	0.15	—	—	V_{DIFF}	—
Absolute Crossing Point Voltage	V_{CROSS}	0.25	—	0.55	V	—
Variation of V_{CROSS} Over All Edges	V_{CROSS_DELTA}	—	—	0.14	V	—
Voltage High for Output Enable	V_{IH_OE}	0.7* V_{DD}	—	—	V	SY75603/4 only
Voltage Low for Output Enable	V_{IL_OE}	—	—	0.3* V_{DD}	V	SY75603/4 only
Input Leakage Current	I_{IL_IN}	–5	—	5	µA	V_{IN} = $V_{IN(MAX)}$, V_{IN} = GND
Input Capacitance	C_{IN}	—	—	5	pF	—

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10%; T_A = –40°C to +105°C, unless noted.

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Input Leakage Current for OExb Inputs (Includes Current due to Pull-Down Resistors)	I_{IL_OE}	–5	—	50	µA	$V_{IN} = V_{DD}$, V_{IN} = GND SY75603/4 only
Single Ended Input Common Mode Voltage (IN_p) (HCSL Common Mode)	V_{SIC}	0.25	—	0.55	V	—
Single Ended Input Voltage Swing for IN_p	V_{SID}	0.3	—	1.45	V	—
Maximum Input Voltage	$V_{IN(MAX)}$	—	—	1.15	V	—
Minimum Input Voltage	$V_{IN(MIN)}$	–0.3	—	—	V	—
Input Frequency (Differential)	f_{IN}	0	—	250	MHz	—
Input Frequency (Single Ended)	f_{IN_SE}	0	—	250	MHz	—
Input Duty Cycle	DC	35	—	65	%	—

Note 1: Tested with 100 MHz clock with outputs driving 5” long trace terminated with 2 pF capacitors to ground.

2: Output Enable control pins are synchronous with the input clock and it takes four rising edges before outputs get enabled and five rising edges before outputs get disabled. Hence the minimum input frequency is greater than 0 Hz. Once the outputs are enabled the input clock frequency can be reduced to 0 Hz.

OUTPUT ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10%; T_A = –40°C to +105°C, C_{LOAD} = 2 pF unless noted.

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Rising Edge Rate	—	1	2.5	4	V/ns	Note 2, Note 3
Falling Edge Rate	—	1	2.5	4	V/ns	Note 2, Note 3
Differential Output High Voltage	V_{OH}	0.6	—	0.9	V	Note 2
Differential Output Low Voltage	V_{OL}	–0.9	—	–0.6	V	Note 2
Absolute Crossing Voltage	V_{CROSS}	0.25	—	0.55	V	Note 1, Note 4, Note 5
Variation of V_{CROSS} Over All Rising Clock Edges	V_{CROSS_DELTA}	—	—	0.14	V	Note 1, Note 4, Note 8
Ring Back Voltage Margin	V_{RB}	–0.1	—	0.1	V	Note 2, Note 10
Time Before V_{RB} is Allowed	t_{STABLE}	500	—	—	ps	Note 2, Note 10
Cycle-to-Cycle Additive Jitter	$t_{CCJITTER}$	—	6.5	8.1	ps	Note 2
Absolute Maximum Output Voltage	V_{MAX}	—	—	1.15	V	Note 1, Note 6
Absolute Minimum Output Voltage	V_{MIN}	–0.3	—	—	V	Note 1, Note 7
Output Duty Cycle	V_{DC}	48	50	52	%	When input has 50% duty cycle and $V_{IN} \geq$ 200 mV, Note 2
Rising to Falling Edge Matching	Rise-Fall Matching	—	—	20	%	Note 1, Note 11
Clock Source DC Impedance (OUTx_p) for part with 85Ω embedded differential series resistance (parts with suffix “A”)	$Z_{C\text{-}DC\_OUT\_p}$	34	—	51	Ω	Note 1, Note 9

OUTPUT ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 3.3V ±10%, 2.5V±10%; 1.8V±10%; T_A = –40°C to +105°C, C_{LOAD} = 2 pF unless noted.

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Clock Source DC Impedance (OUTx_n) for part with 85Ω embedded differential series resistance (parts with suffix “A”)	$Z_{C\text{-}DC\_OUT\_n}$	34	—	51	Ω	Note 1, Note 9
Clock Source DC Impedance (OUTx_p) for part with 100Ω embedded differential series resistance (parts with suffix “B”)	$Z_{C\text{-}DC\_OUT\_p}$	40	—	60	Ω	Note 1, Note 9
Clock Source DC Impedance (OUTx_n) for part with 100Ω embedded differential series resistance (parts with suffix “B”)	$Z_{C\text{-}DC\_OUT\_n}$	40	—	60	Ω	Note 1, Note 9
Output Frequency	F_{MAX}	0	—	250	MHz	—
Output to Output Skew	t_{OOSK}	—	—	30	ps	—
Device to Device Output Skew	t_{POOSK}	—	—	50	ps	—
Input to Output Delay	t_{IOD}	0.9	1.2	1.5	ns	—
Output Enable Time	t_{EN}	—	—	3.5	cycles	Note 12
Output Disable Time	t_{DIS}	—	—	4.5	cycles	Note 12

Note 1: Measurement taken from single ended waveform.

2: Measurement taken from differential waveform.

3: Measured from –150 mV to +150 mV on the differential waveform (derived from OUTx_p to OUTx_n). The signal must be monotonic through the measurement region for rise and fall time. The 300 mV measurement window is centered on the differential zero crossing. See Figure 1-5.

4: Measured at crossing point where the instantaneous voltage value of the rising edge of OUTx_p equals the falling edge of OUTx_n. See Figure 1-1.

5: Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement. See Figure 1-1.

6: Defined as the maximum instantaneous voltage including overshoot. See Figure 1-1.

7: Defined as the minimum instantaneous voltage including undershoot. See Figure 1-1.

8: Defined as the total variation of all crossing voltages of Rising OUTx_p and Falling OUTx_n. This is the maximum allowed variance in V_{CROSS} for any particular system. See Figure 1-2.

9: System board compliance measurements must use the test load card described in Figure 1-7. OUTx_p and OUTx_n are to be measured at the load capacitors C_{LOAD}. Single-ended probes must be used for measurements requiring single-ended measurements. Either single-ended probes with math or differential probe can be used for differential measurements.

10: t_{STABLE} is the time the differential clock must maintain a minimum ±150 mV differential voltage after rising/falling edges before it is allowed to droop back into the V_{RB} ±100 mV differential range. See Figure 1-6.

11: Matching applies to rising edge rate for OUTx_p and falling edge rate for OUTx_n. It is measured using a ±75 mV window centered on the median cross point where OUTx_p rising meets OUTx_n falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The Rise Edge Rate of OUTx_p should be compared to the Fall Edge Rate of OUTx_n; the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 1-3.

12: Output Enable control pins are synchronous with the input clock and it takes four rising edges before outputs get enabled and five rising edges before outputs get disabled. Hence the minimum input frequency is greater than 0 Hz. Once the outputs are enabled the input clock frequency can be reduced to 0 Hz.

JITTER AND PHASE NOISE

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Peak-to-Peak Additive Jitter	p-p A_{JRMS}	—	—	4.5	ps	Note 1, Note 2
Additive Jitter as per PCIe 1.0 (1.5 MHz to 22 MHz)	$t_{jPCIe\_1.0}$	—	0.7	0.8	ps_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 2.0 high band (1.5 MHz to 50 MHz)	$t_{jPCIe\_2.0\_high}$	—	70	90	fs_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 2.0 low band (10 kHz to 1.5 MHz)	$t_{jPCIe\_2.0\_low}$	—	14	20	fs_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 2.0 mid band (5 MHz to 16 MHz)	$t_{jPCIe\_2.0\_mid}$	—	55	74	fs_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 3.0 (PLL_BW = 2 to 5 MHz, CDR = 10 MHz)	$t_{jPCIe\_3.0}$	—	18	22	fs_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 4.0 (PLL_BW = 2 to 5 MHz, CDR = 10 MHz)	$t_{jPCIe\_4.0}$	—	18	22	fs_{RMS}	Note 1, Note 2
Additive Jitter as per PCIe 5.0 (PLL_BW = 0.5 to 1.8 MHz, CDR for 32 GT/s CC)	$t_{jPCIe\_5.0}$	—	7	10	fs_{RMS}	Note 2, Note 3
Additive Jitter as per PCIe 6.0 (PLL_BW = 0.5 to 1 MHz, CDR for 64 GT/s CC)	$t_{jPCIe\_6.0}$	—	4.5	6	fs_{RMS}	Note 2, Note 3
Additive jitter as per Intel QPI 9.6 Gbps	t_{jQPI}	—	35	45	fs_{RMS}	Note 1, Note 2
Additive RMS jitter in 1 MHz to 20 MHz band	$t_{j\_1M\_20M}$	—	51	66	fs_{RMS}	Note 1, Note 2 (100 MHz clock)
		—	40	54	fs_{RMS}	Note 1, Note 2 (133 MHz clock)
Additive RMS jitter in 12 kHz to 20 MHz band	tj_12k_20M	—	52	68	fs_{RMS}	Note 1, Note 2 (100 MHz clock)
		—	44	58	fs_{RMS}	Note 1, Note 2 (133 MHz clock)
Noise Floor	NF	—	–165	–163	dBc/Hz	Note 1, Note 2 (100 MHz clock)
		—	–165	–163	dBc/Hz	Note 1, Note 2 (133 MHz clock)

Note 1: Measured into AC test load as per Figure 1-7.

2: Measured from differential crossing point to differential crossing point.

3: Measured with 50Ω termination in instrument without a test load.

TEMPERATURE SPECIFICATIONS

Parameters	Symbol	Min.	Typ.		Max.	Unit	Condition
Temperature Ranges							
Ambient Operating Temperature Range	T_A	–40	—		+105	°C	—
Storage Temperature Range	T_S	–65	—		+150	°C	—
Package Thermal Resistances			**VDFN 8-Ld**	**VQFN 16-Ld**			
Junction-to-Ambient Thermal Resistance	θ_{JA}	—	138	35.7	—	°C/W	Still air
		—	132	30.8	—		1m/s airflow
		—	127	28.6	—		2.5m/s airflow
Junction-to-Board Thermal Resistance	θ_{JB}	—	104	5	—	°C/W	—
Junction-to-Case Thermal Resistance	θ_{JC}	—	105	49.5	—	°C/W	—
Thermal Characterization, Junction-to-Top of Package	Ψ_{JT}	—	11.5	3	—	°C/W	Still air

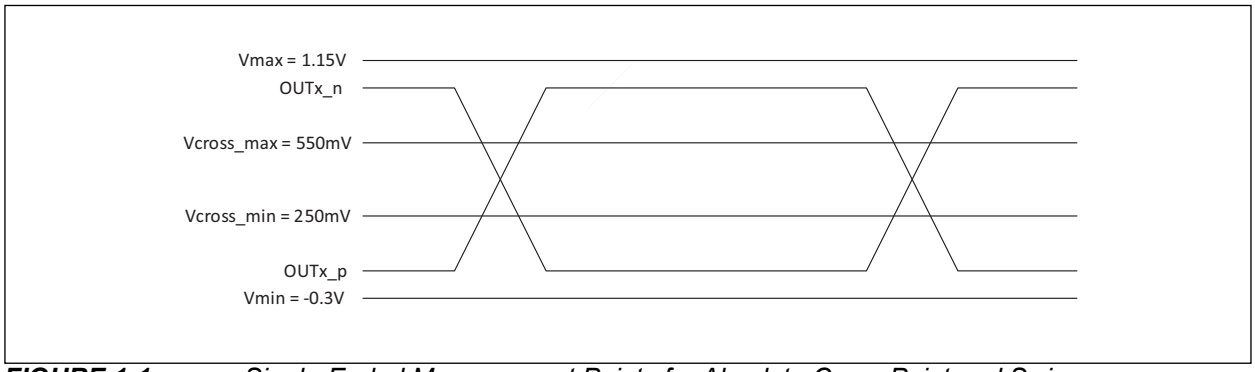


FIGURE 1-1: *Single-Ended Measurement Points for Absolute Cross Point and Swing.*

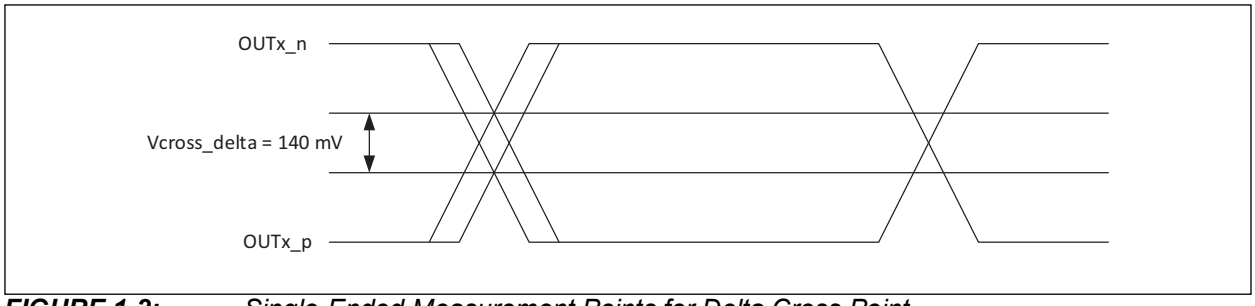


FIGURE 1-2: *Single-Ended Measurement Points for Delta Cross Point.*

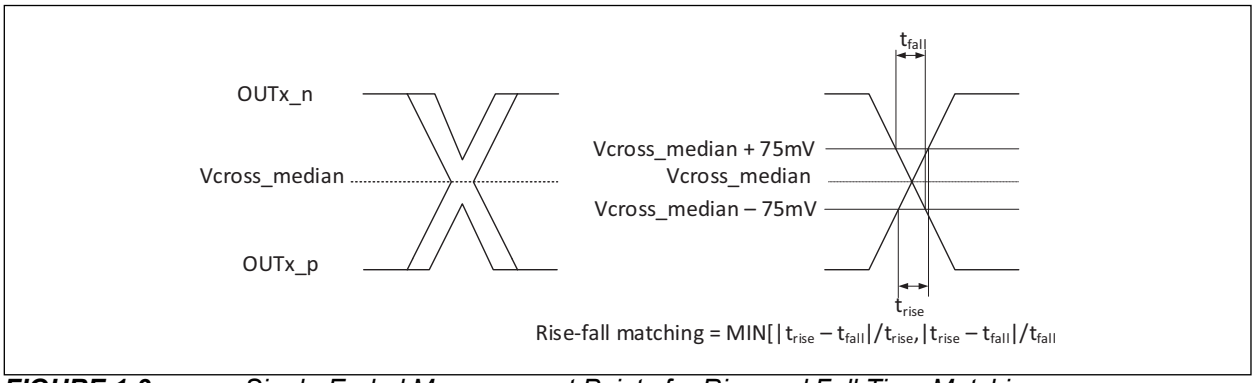


FIGURE 1-3: *Single-Ended Measurement Points for Rise and Fall Time Matching.*

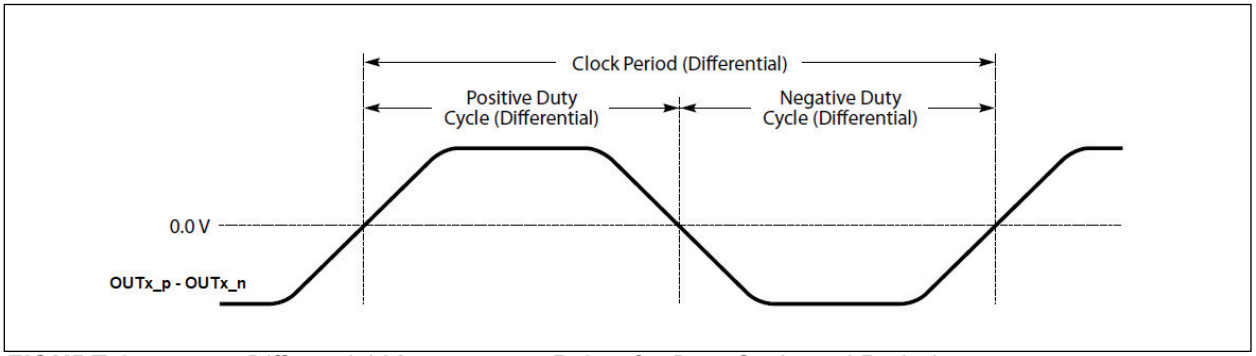


FIGURE 1-4: *Differential Measurement Points for Duty Cycle and Period.*

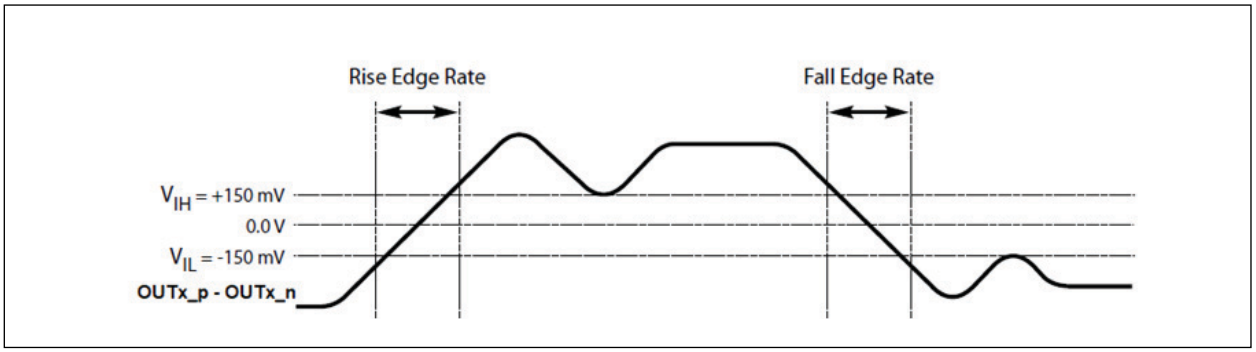


FIGURE 1-5: *Differential Measurement Points for Rise and Fall Time.*

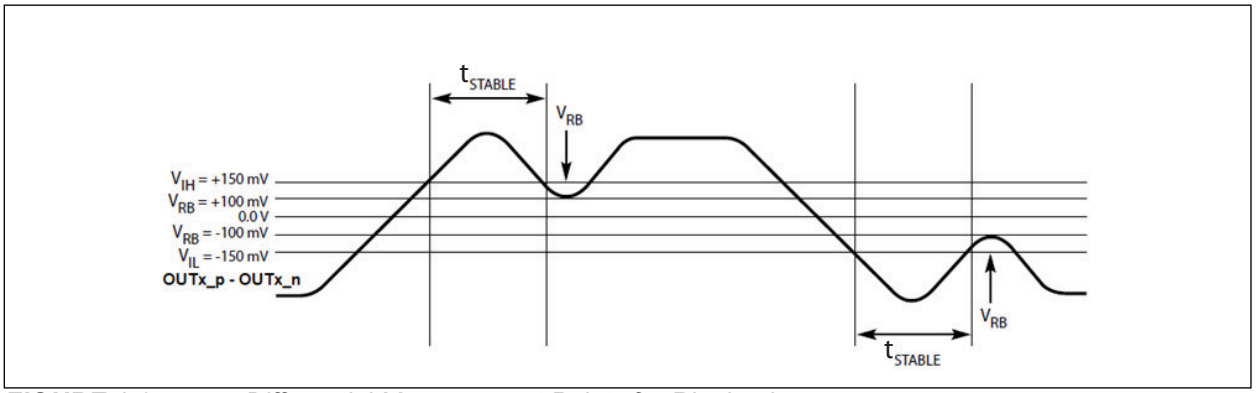


FIGURE 1-6: *Differential Measurement Points for Ringback.*

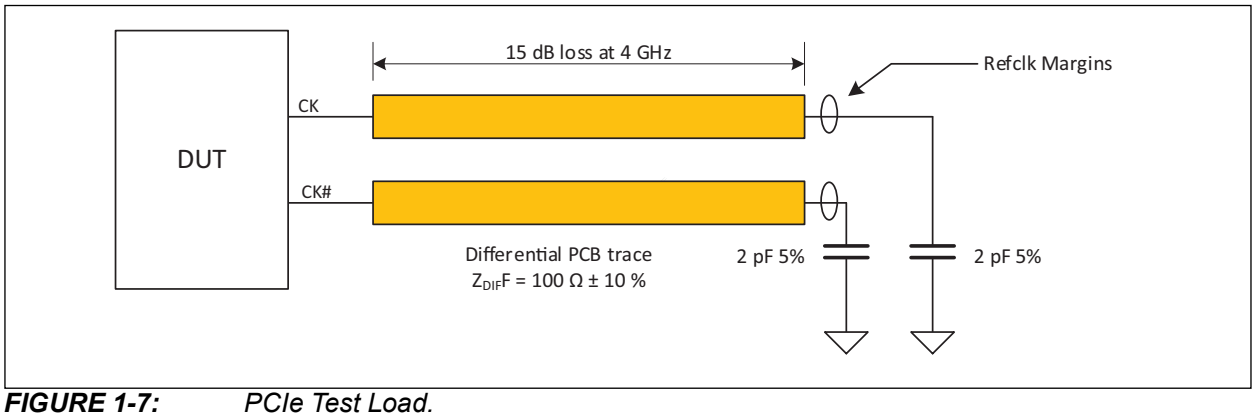


FIGURE 1-7: *PCIe Test Load.*

2.0 TYPICAL OPERATING CHARACTERISTICS

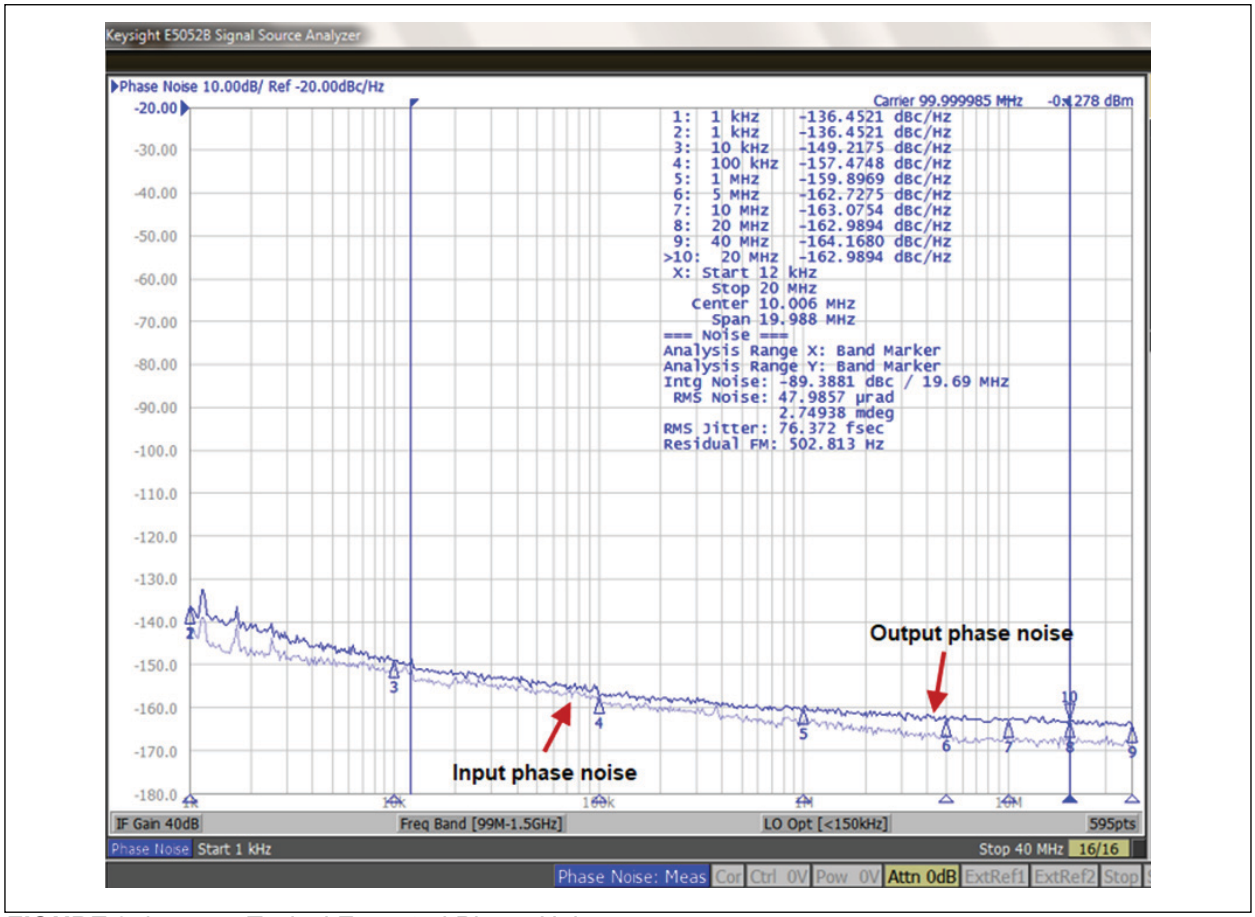


FIGURE 2-1: *Typical Expected Phase Noise.*

3.0 PIN DESCRIPTIONS

All device inputs and outputs are LP-HCSL unless described otherwise. The Type column uses the following symbols:

• I: Input

• IPD: Input with 100 kΩ internal pull-down resistor

• O: Output

• P: Power supply

The descriptions of the pins are listed in Table 3-1 and Table 3-2.

TABLE 3-1: SY75602A/02B PIN FUNCTION TABLE

Pin Number	Pin Name	Type	Description
Input Reference			
1	IN_p	I	**Differential/Single Ended Input Reference** Input frequency range >0 Hz to 250 MHz. **Note 1:** >0 Hz means frequency higher than DC. On the power up, the device needs four clock cycles before the outputs get enabled. This feature filters any initial glitch or runt pulse from the clock source. **Note 2:** The differential input has hysteresis of 30 mV that prevents outputs from randomly toggling when both p and n inputs are at the same voltage level. For example, when p and n inputs are held low as in the case when the buffer is driven from an HCSL driver that is disabled.
2	IN_n		
Output Clocks			
3	OUT0_p	O	**Ultra-Low Additive Jitter Differential Outputs 0 and 1** Output frequency range >0 Hz to 250 MHz.
4	OUT0_n		
6	OUT1_p		
7	OUT1_n		
Power and Ground			
8	VDD	P	**Positive Supply Voltage:** Connect to either 3.3V, 2.5V, or 1.8V supply.
5	GND	P	**Ground:** Connect to ground.

TABLE 3-2: SY75604A/04B AND SY75603A/03B PIN FUNCTION TABLE

Pin Number	Pin Name SY75604A/04B	Pin Name SY75603A/03B	Type	Description
Input Reference				
1	IN_p	IN_p	I	**Differential/Single Ended Input Reference** Input frequency range >0 Hz to 250 MHz **Note 1:** >0 Hz means frequency higher than DC. Output Enable control pins (OExb) need four clock cycles before the corresponding output get enabled/disable. This feature ensures glitch free transition of the outputs. **Note 2:** The differential input has hysteresis of 30 mV that prevents outputs from randomly toggling when both p and n inputs are at the same voltage level. For example, when p and n inputs are held low as in the case when the buffer is driven from an HCSL driver that is disabled.
2	IN_n	IN_n		
Output Clocks				
4	OUT0_p	NC	O	**Ultra-Low Additive Jitter Differential Outputs 0 to 1 (SY75603A/03B) and 0 to 3 (SY75604A/04B)** Output frequency range >0 Hz to 250 MHz NC are no connect pins. They are not bonded to the die but they should be soldered to the board for mechanical reasons.
5	OUT0_n	NC		
7	OUT1_p	NC		
8	OUT1_n	NC		
10	OUT2_p	OUT0_p		
11	OUT2_n	OUT0_n		
14	OUT3_p	OUT1_p		
15	OUT3_n	OUT1_n		
Control Inputs				
3	OE0b	NC	IPD	**Output Enable Control** When OExb is low the output x where x = {0,1} for SY75603A/03B and x = {0,1,2,3} for SY75604A/04B is active. OExb is synchronous and it takes 3.5 clock cycles of the input clock to enable and 4.5 clock to disable the output. OExb pins are pulled-down with 100 kΩ resistor NC are no connect pins. They are not bonded to the die but they should be soldered to the board for mechanical reasons.
6	OE1b	NC		
12	OE2b	OE0b		
16	OE3b	OE1b		
Power and Ground				
13	VDD	VDD	P	**Positive Supply Voltage:** Connect to either 3.3V, 2.5V, or 1.8V supply.
9 ePad	GND	GND	P	**Ground:** Connect to ground.

4.0 FUNCTIONAL DESCRIPTION

The SY75602A/02B/603A/03B/604A/04B are PCIe clock buffers with ultra-low additive jitter. They can be used in all PCIe 1/2/3/4/5/6 common clock and SRIS applications.

SY75602A/02B are the industry's smallest (1.4 mm x 1.6 mm VDFN) two output PCIe clock buffers.

SY75603A/03B and SY75604A/04B are two and four output PCIe clock buffers with glitch free per-output enable/disable control hardware pins. Both devices are packaged in 3 mm x 3 mm VQFN.

The devices have embedded low-dropout regulators (LDO) for superior power noise supply rejection. They support 1.8V, 2.5V, and 3.3V supplies with tolerance of ±10% which exceeds ±9% required by PCIe Card Electro Mechanical Specification.

4.1 Clock Input

Please refer to the Functional Block Diagrams on how to terminate different signals fed to the input of the device.

Figure 4-1 and Figure 4-2 show how to terminate input of the device in most common cases: Low Power HCSL (LPHCSL), HCSL, and single-ended LVCMOS.

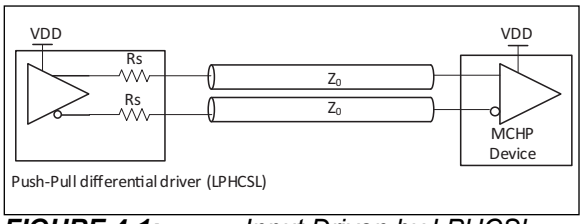


FIGURE 4-1: *Input Driven by LPHCSL Driver.*

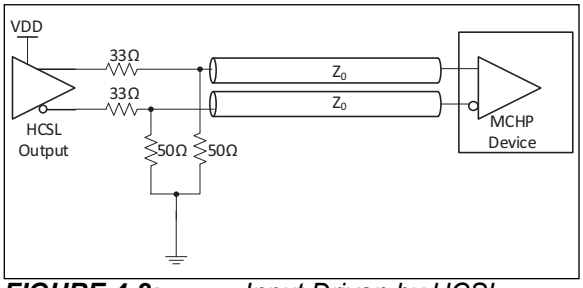


FIGURE 4-2: *Input Driven by HCSL Driver.*

Figure 4-3 shows how to terminate a single-ended output, such as LVCMOS. This example assumes 50Ω transmission line which is the most common for single ended CMOS signaling. Ideally, resistors R1 and R2 should be 100Ω each and R_O + R_S should be 50Ω so that the transmission line is terminated at both ends with characteristic impedance. If the driving strength of the output driver is not sufficient to drive low impedance, the value of series resistor R_S should be increased. This will reduce the voltage swing at the input but this should be fine as long as the input voltage swing requirement is not violated (0.3V). The source resistors of R_S = 270Ω could be used for standard LVCMOS driver. This will provide 516 mV of voltage swing for 3.3V LVCMOS driver with load current of (3.3V/2) * (1/(270Ω + 50Ω)) = 5.16 mA.

For optimum performance both differential input pins (_p and _n) need to be DC biased to the same voltage. Hence, the ratio R1/R2 should be equal to the ratio R3/R4.

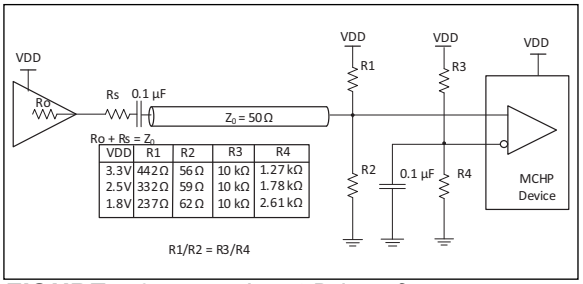


FIGURE 4-3: *Input Driven from a Single-Ended CMOS Output.*

The differential input has hysteresis of 30 mV that prevents outputs from randomly toggling when both p and n inputs are at the same voltage level. For example, when p and n inputs are held low as in the case when the buffer is driven from an HCSL driver that is disabled.

4.2 Clock Outputs

Differential outputs have embedded termination resistors as shown in Figure 4-4. This provides significant saving relative to traditional current based HCSL outputs which require four resistors per differential output.

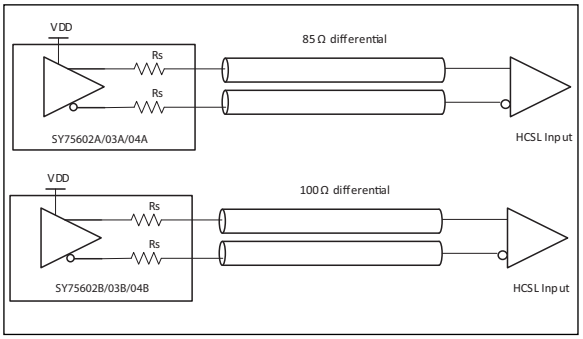


FIGURE 4-4: *Terminating Differential Outputs.*

Embedded termination resistors in SY75602A/603A/604A are matched for 85Ω and embedded termination resistors in SY75602B/603B/604B are matched for 100Ω differential transmission line.

4.3 Output Enable

Each output of SY75603A/03B/04A/04B has an active low Output Enable (OExb) control pin. Output Enable and Disable function is synchronous with the input clock which results in glitchless transitions as shown in Figure 4-5 and Figure 4-6. The OExb is sampled on the falling edge of the differential input (or falling edge of IN_p signal). It takes 3.5 clock cycles of the input clock to enable an output and 4.5 clock cycles to disable the output, after the change of OExb is sampled.

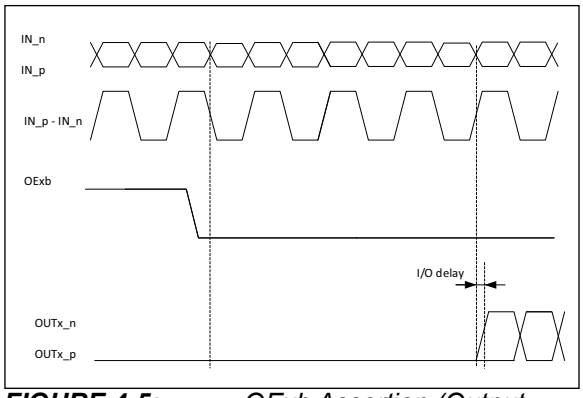


FIGURE 4-5: *OExb Assertion (Output Enable) Timing Diagram.*

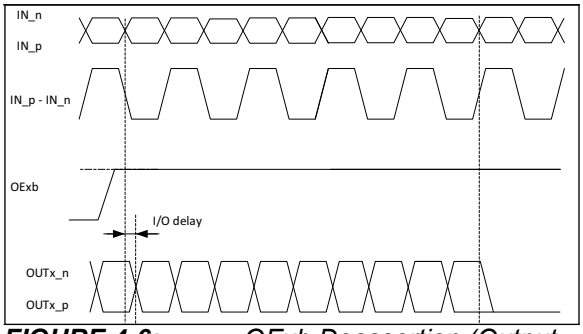
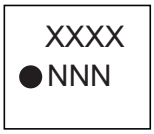


FIGURE 4-6: *OExb Deassertion (Output Disable) Timing Diagram.*

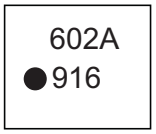
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

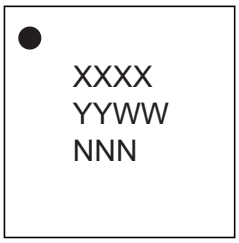
8-Lead VDFN*



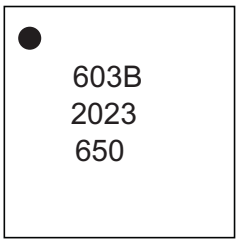
Example



16-Lead VQFN*



Example

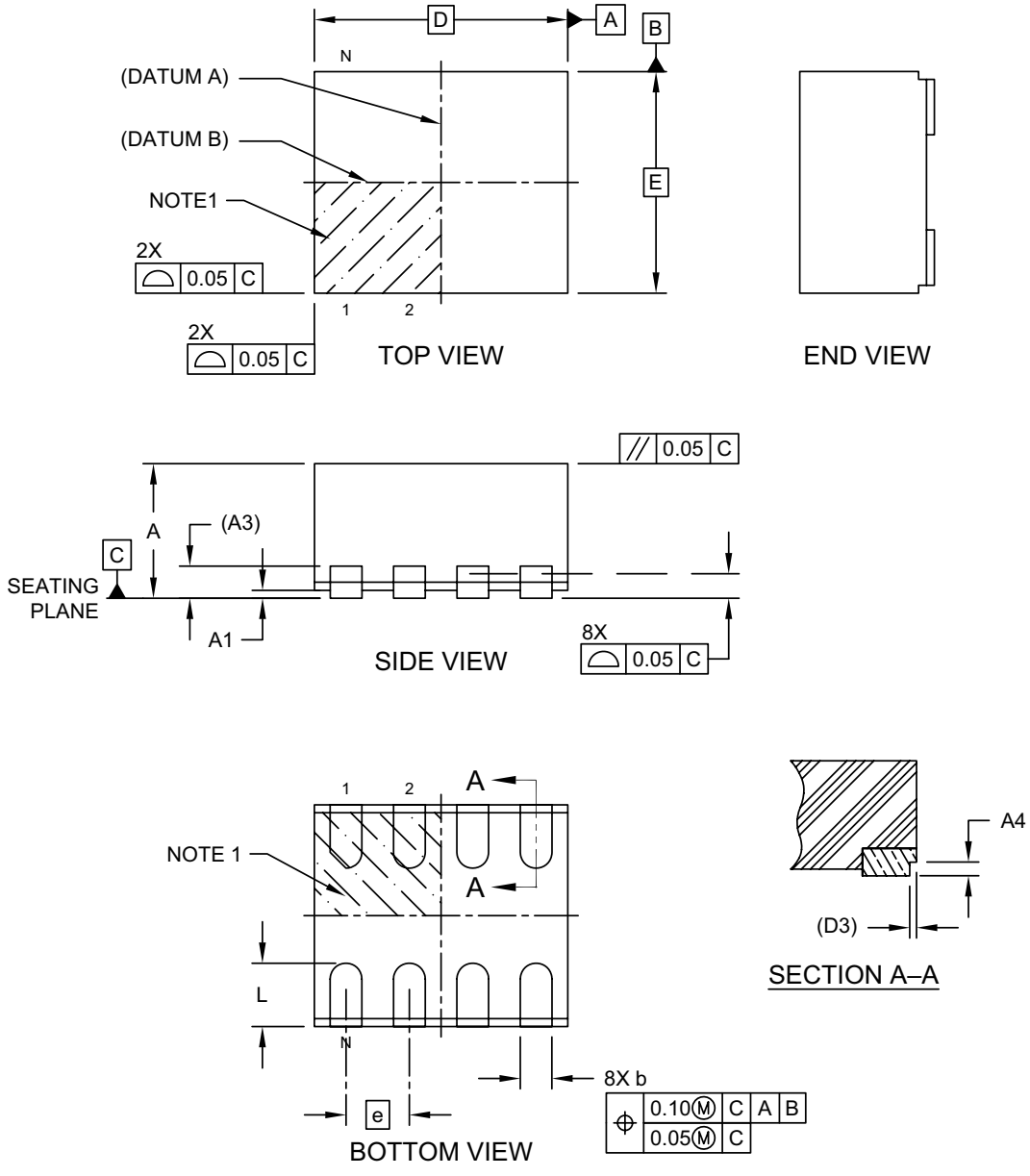


Legend:	XX...X	Product code or customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	●, ▲, ▼	Pin one index is identified by a dot, delta up, or delta down (triangle mark).
Note:	In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.	
	Underbar (_) and/or Overbar (¯) symbol may not be to scale.	

8-Lead VDFN 1.6 mm x 1.4 mm Package Outline and Recommended Land Pattern

8-Lead Very Thin Dual Flat, No Lead Package (NNC) - 1.6x1.4x0.9 mm Body [VDFN] With Stepped Wettable Flanks

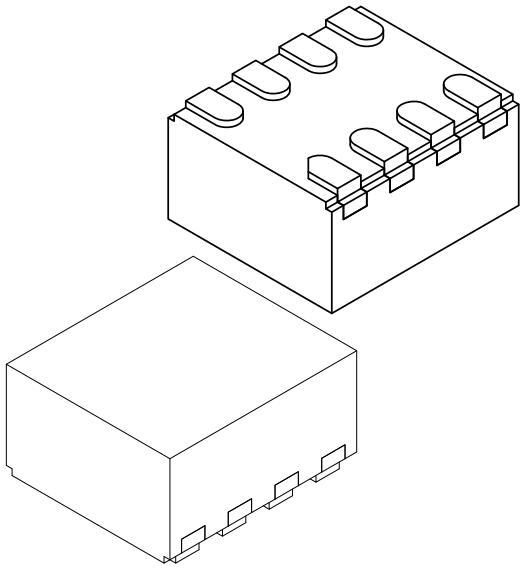
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-25509 Rev A Sheet 1 of 2

8-Lead Very Thin Dual Flat, No Lead Package (NNC) - 1.6x1.4x0.9 mm Body [VDFN]
With Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	e		0.40 BSC	
Overall Height	A	0.80	0.85	0.90
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.203 REF	
Overall Length	D		1.60 BSC	
Overall Width	E		1.40 BSC	
Terminal Width	b	0.15	0.20	0.25
Terminal Length	L	0.30	0.40	0.50
Wettable Flank Step Length	D3		0.05 REF	
Wettable Flank Step Height	A4	0.10	–	–

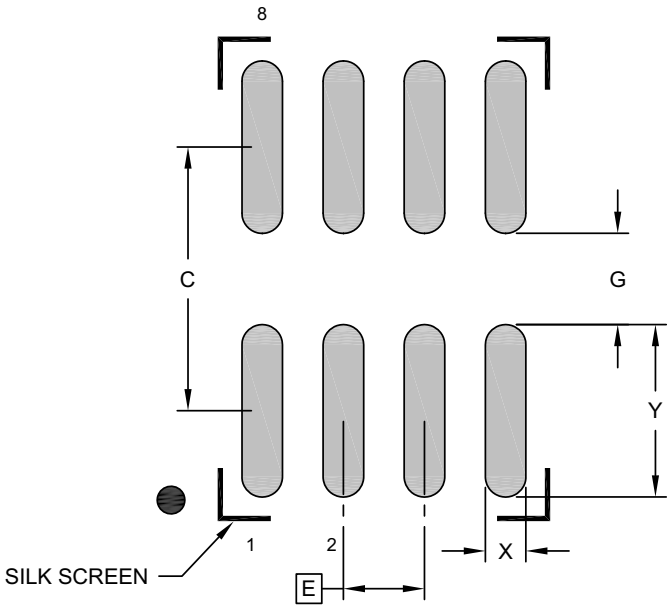
Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-25509 Rev A Sheet 2 of 2

8-Lead Very Thin Dual Flat, No Lead Package (NNC) - 1.6x1.4x0.9 mm Body [VDFN]
With Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.40 BSC	
Contact Pad Spacing	C		1.30	
Contact Pad Width (Xnn)	X			0.20
Contact Pad Length (Xnn)	Y			0.85
Contact Pad to Contact Pad (Xnn)	G	0.45		

Notes:

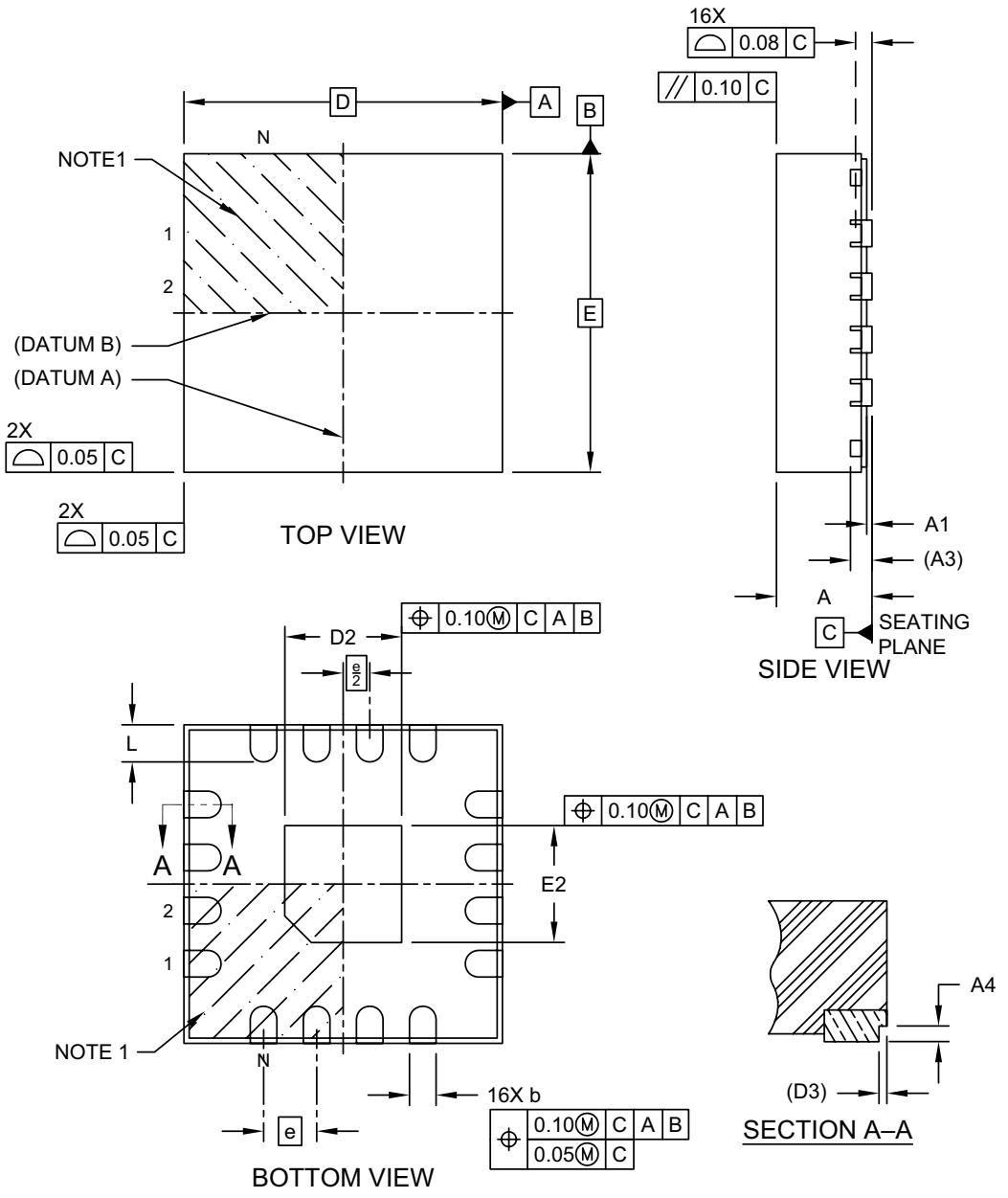
1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-27509 Rev A

16-Lead VQFN 3.0 mm x 3.0 mm Package Outline and Recommended Land Pattern

16-Lead Very Thin Quad Flat, No Lead Package (4MX) - 3x3x0.9 mm Body [VQFN]
With 1.10 mm Exposed Pad and Stepped Wettable Flanks

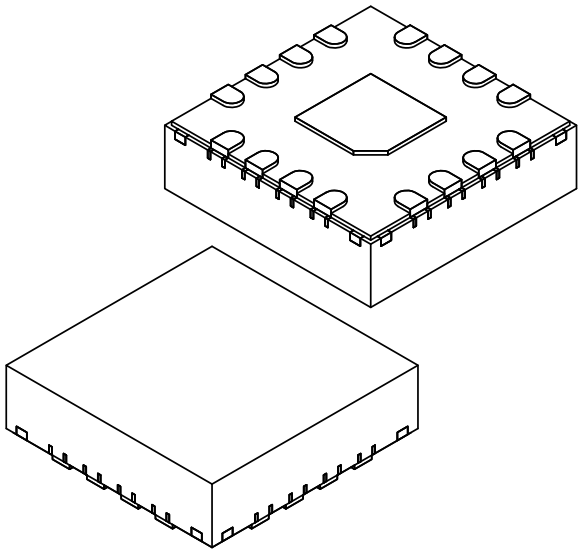
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-508 Rev A Sheet 1 of 2

16-Lead Very Thin Quad Flat, No Lead Package (4MX) - 3x3x0.9 mm Body [VQFN]
With 1.10 mm Exposed Pad and Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		16	
Pitch	e		0.50 BSC	
Overall Height	A	0.80	0.85	0.90
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.203 REF	
Overall Length	D		3.00 BSC	
Exposed Pad Length	D2	1.00	1.10	1.20
Overall Width	E		3.00 BSC	
Exposed Pad Width	E2	1.00	1.10	1.20
Terminal Width	b	0.20	0.25	0.30
Terminal Length	L	0.25	0.35	0.45
Wettable Flank Step Length	D3		0.05 REF	
Wettable Flank Step Height	A4	0.10	-	0.19

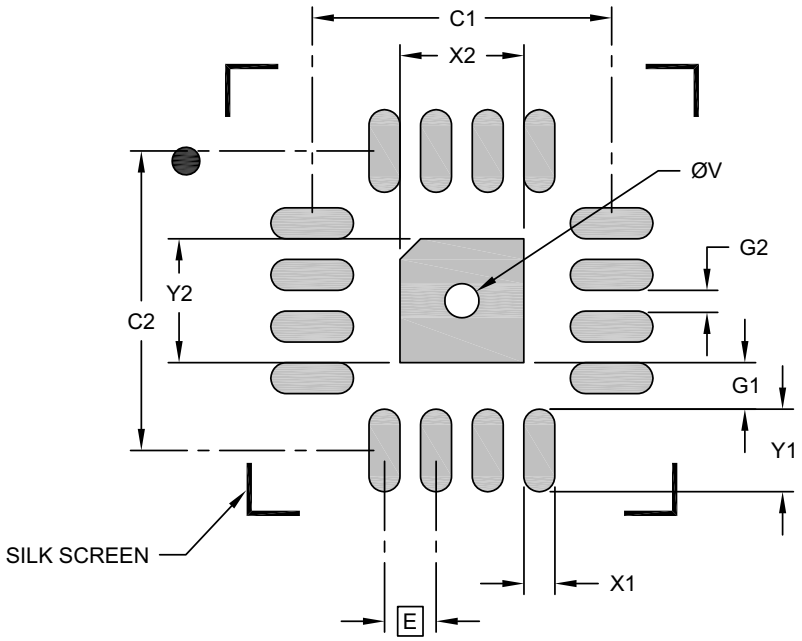
Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-508 Rev A Sheet 2 of 2

16-Lead Very Thin Quad Flat, No Lead Package (4MX) - 3x3x0.9 mm Body [VQFN]
With 1.10 mm Exposed Pad and Stepped Wettable Flanks

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.50 BSC	
Optional Center Pad Width	X2			1.20
Optional Center Pad Length	Y2			1.20
Contact Pad Spacing	C1		2.90	
Contact Pad Spacing	C2		2.90	
Contact Pad Width (X16)	X1			0.30
Contact Pad Length (X16)	Y1			0.80
Contact Pad to Center Pad (X16)	G1	0.45		
Contact Pad to Contact Pad (X12)	G2	0.20		
Thermal Via Diameter	V		0.33	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2508 Rev A

APPENDIX A: REVISION HISTORY

Revision A (September 2021)

- Initial release of SY75602A/02B/603A/03B/604A/04B as Microchip data sheet DS20006508A.

Revision B (October 2021)

- Updated various values in the Electrical Characteristics, Output Electrical Characteristics, and Jitter and Phase Noise tables.
- Updated Note 12 in the Output Electrical Characteristics table.
- Updated Input Reference description in Table 3-1 and Table 3-2.
- Updated Control Inputs description in Table 3-2.
- Added paragraph immediately after Figure 4-3.

Revision C (July 2022)

- Added information specific to the 85Ω devices to the Current Consumption section of the Electrical Characteristics table.

Revision D (May 2023)

- Added PCIe Gen6 information to Features, General Description, and Jitter and Phase Noise.
- Added temperature range information to the Temp Spec table.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	XXX	[-XX]
Device	Package	Media Type

Device:	SY75602A:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 85Ω Clock Buffer
	SY75602B:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 100Ω Clock Buffer
	SY75603A:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 85Ω Clock Buffer
	SY75603B:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 100Ω Clock Buffer
	SY75604A:	4 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 85Ω Clock Buffer
	SY75604B:	4 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 100Ω Clock Buffer
Package:	TWL =	8-Lead 1.4 mm x 1.6 mm VDFN (Wettable Flank)
	TWL =	16-Lead 3 mm x 3 mm VQFN (Wettable Flank)
Media Type:	<blank> =	120/Tube
	TR =	2,000/Reel (8-Lead Package Option)
	TR =	3,300/Reel (16-Lead Package Option)

Examples:

a) SY75603ATWL:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 85Ω Clock Buffer, 16-Lead 3 mm x 3 mm VQFN, 120/Tube
b) SY75602BTWL-TR:	2 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 100Ω Clock Buffer, 8-Lead 1.4 mm x 1.6 mm VDFN, 2,000/Reel
c) SY75604ATWL-TR:	4 Output Ultra-Low Additive Jitter PCIe 1/2/3/4/5/6 85Ω Clock Buffer, 16-Lead 3 mm x 3 mm VQFN, 3,300/Reel

Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

NOTES:

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